onsemi

MARKING DIAGRAMS

TinyLogic HST 2-Input NAND Gate

NC7ST00

Description

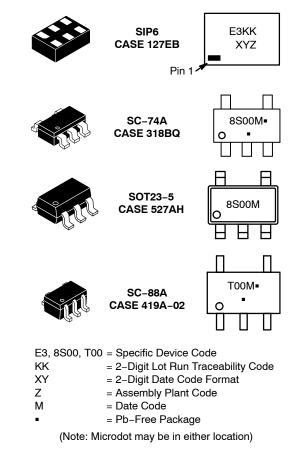
The NC7ST00 is a single 2–Input high performance CMOS NAND Gate, with TTL-compatible inputs. Advanced Silicon Gate CMOS fabrication assures high speed and low power circuit operation. ESD protection diodes inherently guard both inputs and output with respect to the V_{CC} and GND rails. High gain circuitry offers high noise immunity and reduced sensitivity to input edge rate. The TTL-compatible inputs facilitate TTL to NMOS / CMOS interfacing. Device performance is similar to MM74HCT but with 1/2 the output current drive of HC / HCT.

Features

- Space Saving SOT23-5, SC-74A and SC-88A 5-Lead Package
- Ultra Small MicroPakTM Leadless Package
- High Speed: $t_{PD} < 7$ ns Typ, $V_{CC} = 5$ V, $C_L = 15$ pF
- Low Quiescent Power: $I_{CC} < 1 \mu A$ Typ, $V_{CC} = 5.5 V$
- Balanced Output Drive: 2 mA IOL, -2 mA IOH
- TTL-compatible Inputs
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



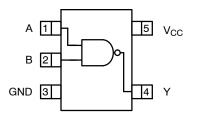
Figure 1. Logic Symbol

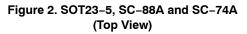


ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 4 of this data sheet.

Pin Configurations





PIN DESCRIPTIONS

| Pin Names | Description |
|-----------|-------------|
| A, B | Inputs |
| Y | Output |
| NC | No Connect |

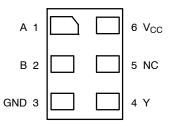


Figure 3. MicroPak (Top Through View)

FUNCTION TABLE $(Y = \overline{AB})$

| Inputs | | Output |
|--------|---|--------|
| А | В | Y |
| L | L | Н |
| L | Н | Н |
| н | L | Н |
| Н | Н | L |

H = HIGH Logic Level L = LOW Logic Level

| Symbol | Parameter | | Min | Max | Unit |
|-------------------------------------|--|------------------------------------|------|-----------------------|------|
| V _{CC} | Supply Voltage | | -0.5 | 6.5 | V |
| I _{IK} | DC Input Diode Current | V _{IN} < 0 V | - | -20 | mA |
| | | V _{IN} > V _{CC} | - | +20 | |
| V _{IN} | DC Input Voltage | • | -0.5 | V _{CC} + 0.5 | V |
| Ι _{ΟΚ} | DC Output Diode Current | V _{OUT} < 0 V | - | -20 | mA |
| | | V _{OUT} > V _{CC} | - | +20 | |
| V _{OUT} | Output Voltage | | -0.5 | V _{CC} + 0.5 | V |
| I _{OUT} | DC Output Source or Sink Current | | - | ±12.5 | mA |
| I _{CC} or I _{GND} | DC V _{CC} or Ground Current per Suppl | y Pin | - | ±25 | mA |
| T _{STG} | Storage Temperature | | -65 | +150 | °C |
| ТJ | Junction Temperature | | - | +150 | °C |
| ΤL | Lead Temperature (Soldering, 10 Seconds) | | - | +260 | °C |
| PD | Power Dissipation in Still Air | SC-74A / SOT23-5 | - | 390 | mW |
| | | SC-88A | - | 332 | |
| | | MicroPak-6 | - | 812 | |

ABSOLUTE MAXIMUM RATINGS

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------------------|--------------------------|-------------------------|-----|-----------------|------|
| V _{CC} | Supply Voltage | | 4.5 | 5.5 | V |
| V _{IN} | Input Voltage | | 0 | V _{CC} | V |
| V _{OUT} | Output Voltage | | 0 | V _{CC} | V |
| T _A | Operating Temperature | | -40 | +85 | °C |
| t _r , t _f | Input Rise and Fall Time | V _{CC} = 5.0 V | 0 | 10 | ns/V |
| θ_{JA} | Thermal Resistance | SC-74A / SOT23-5 | - | 320 | °C/W |
| | | SC-88A | - | 377 | |
| | | MicroPak-6 | - | 154 | |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

1. Unused inputs must be held HIGH or LOW. They may not float.

DC ELECTICAL CHARACTERISTICS

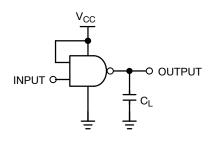
| | | | | - | T _A = +25°C | ; | T _A = -40 | to +85°C | |
|------------------|---------------------------|---------------------|---|-------------|------------------------|-------------|----------------------|-------------|------|
| Symbol | Parameter | V _{CC} (V) | Conditions | Min | Тур | Max | Min | Max | Unit |
| V _{IH} | HIGH Level Input Voltage | 4.5 – 5.5 | | 2.0 | - | - | 2.0 | - | V |
| V _{IL} | LOW Level Input Voltage | 4.5 – 5.5 | | - | - | 0.8 | - | 0.8 | V |
| V _{OH} | HIGH Level Output Voltage | 4.5 4.5 | $\begin{split} I_{OH} &= -20 \ \mu A \\ I_{OH} &= -2 \ m A \\ V_{IN} &= V_{IH} \ or \ V_{IL} \end{split}$ | 4.4 4.18 | 4.5 4.35 | _ | 4.4 4.13 | - | V |
| V _{OL} | LOW Level Output Voltage | 4.5 4.5 | $I_{OL} = 20 \ \mu A$ $I_{OL} = 2 \ m A$ $V_{IN} = V_{IH} \ or \ V_{IL}$ | _ | 0 0.10 | 0.1 0.26 | - | 0.1 0.33 | V |
| I _{IN} | Input Leakage Current | 5.5 | $0 \leq V_{IN} \leq 5.5 \ V$ | - | - | ±0.1 | - | ±1.0 | μA |
| I _{CC} | Quiescent Supply Current | 5.5 | $V_{IN} = V_{CC}$ or GND | - | - | 1.0 | - | 10.0 | μA |
| I _{CCT} | I _{CC} per Input | 5.5 | One Input $V_{IN} = 0.5 \text{ V or}$ 2.4 V, Other Input V_{CC} or GND | - | _ | 2.0 | _ | 2.9 | mA |

AC ELECTRICAL CHARACTERISTICS

| | | | | | T _A = +25°C | 2 | T _A = -40 | to +85°C | |
|-------------------------------------|---|---------------------|------------------------|-----|------------------------|-----|----------------------|----------|------|
| Symbol | Parameter | V _{CC} (V) | Conditions | Min | Тур | Max | Min | Max | Unit |
| t _{PLH} , t _{PHL} | Propagation Delay (Figure 4, 6) | 5.0 | C _L = 15 pF | - | 3.4 | 12 | - | - | ns |
| | | | | - | 6.3 | 17 | - | - | |
| | | 4.5 | C _L = 50 pF | - | 6.0 | 16 | - | 20 | |
| | | | | - | 11.5 | 27 | - | 31 | |
| | | 5.5 | 1 | - | 4.1 | 14 | - | 18 | |
| | | | | - | 11.2 | 26 | - | 30 | |
| t _{TLH} , t _{THL} | Output Transition Time | 5.0 | C _L = 15 pF | - | 4 | 10 | - | - | ns |
| | (Figure 4, 6) | 4.5 | C _L = 50 pF | - | 11 | 25 | - | 31 | |
| | | 5.5 | | - | 10 | 21 | - | 26 | |
| C _{IN} | Input Capacitance | Open | | - | 2 | 10 | - | - | pF |
| C _{PD} | Power Dissipation Capacitance (Figure 5) | 5.0 | (Note 2) | - | 6 | - | - | - | pF |

C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current. Current consumption (I_{CCD}) at no output loading and operating at 50% duty cycle. (See Figure 5). C_{PD} is related to I_{CCD} dynamic operating current by the expression: I_{CCD} = (C_{PD}) (V_{CC}) (f_{IN}) + (I_{CCstatic}).

AC Loading and Waveforms



 C_L includes load and stray capacitance Input PRR = 1.0 MHz, t_W = 500 ns

Figure 4. AC Test Circuit

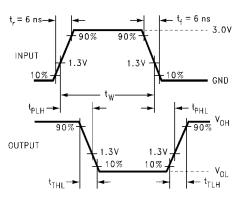
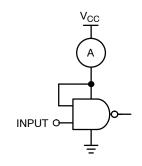


Figure 6. AC Waveforms



Input = AC Waveform; PRR = Variable; Duty Cycle = 50%.

Figure 5. I_{CCD} Test Circuit

| Device | Top Mark | Packages | Shipping [†] |
|-------------------|----------|----------------|-----------------------|
| NC7ST00M5X | 8S00 | SC-74A | 3000 / Tape & Reel |
| NC7ST00M5X-L22090 | 8S00 | SOT23-5 | 3000 / Tape & Reel |
| NC7ST00P5X | T00 | SC-88A | 3000 / Tape & Reel |
| NC7ST00P5X-L22057 | T00 | SC-88A | 3000 / Tape & Reel |
| NC7ST00L6X | E3 | SIP6, MicroPak | 5000 / Tape & Reel |
| NC7ST00L6X-L22175 | E3 | SIP6, MicroPak | 5000 / Tape & Reel |

ORDERING INFORMATION

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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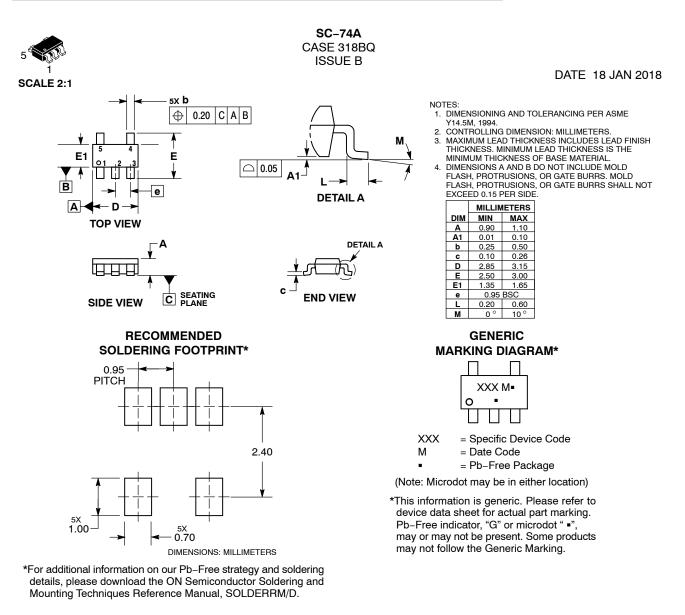


SIP6 1.45X1.0 CASE 127EB ISSUE O

DATE 31 AUG 2016







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|---|--|--|---|
| DESCRIPTION: | SC-74A | | PAGE 1 OF 1 |
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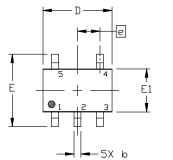
SC-88A (SC-70-5/SOT-353) CASE 419A-02 **ISSUE M**

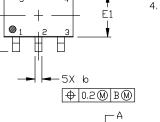
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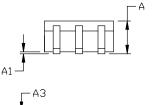
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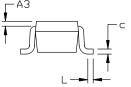
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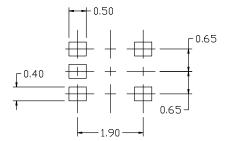
DATE 11 APR 2023











RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

| DIM | MILLIMETERS | | | |
|-----|-------------|------|------|--|
| MIU | MIN. | NDM. | MAX. | |
| A | 0.80 | 0.95 | 1.10 | |
| A1 | | | 0.10 | |
| A3 | 0.20 REF | | | |
| b | 0.10 | 0.20 | 0.30 | |
| С | 0.10 | | 0.25 | |
| D | 1.80 | 2.00 | 5'50 | |
| E | 2.00 | 2.10 | 5'50 | |
| E1 | 1.15 | 1.25 | 1.35 | |
| e | 0.65 BSC | | | |
| L | 0.10 | 0.15 | 0.30 | |

DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH,

PROTRUSIONS, OR GATE BURRS.MOLD FLASH, PROTRUSIONS,

OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.

CONTROLLING DIMENSION: MILLIMETERS 419A-01 DBSOLETE, NEW STANDARD 419A-02

GENERIC MARKING





*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

XXX = Specific Device Code

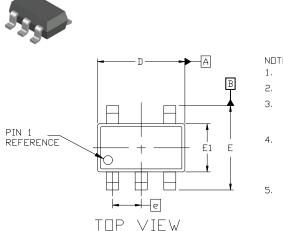
Μ = Date Code = Pb-Free Package

(Note: Microdot may be in either location)

| STYLE 1: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 5. COLLECTOR | STYLE 2: PIN 1. ANODE 2. EMITTER 3. BASE 4. COLLECTOR 5. CATHODE | STYLE 3: PIN 1. ANODE 1 2. N/C 3. ANODE 2 4. CATHODE 2 5. CATHODE 1 | STYLE 4: PIN 1. SOURCE 1 2. DRAIN 1/2 3. SOURCE 1 4. GATE 1 5. GATE 2 | STYLE 5: PIN 1. CATHODE 2. COMMON ANOD 3. CATHODE 2 4. CATHODE 3 5. CATHODE 4 | E |
|--|--|--|--|--|---|
| STYLE 6: PIN 1. EMITTER 2 2. BASE 2 3. EMITTER 1 4. COLLECTOR 5. COLLECTOR 2/BASE | STYLE 7: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 1 5. COLLECTOR | STYLE 8: PIN 1. CATHODE 2. COLLECTOR 3. N/C 4. BASE 5. EMITTER | STYLE 9: PIN 1. ANODE 2. CATHODE 3. ANODE 4. ANODE 5. ANODE | Note: Please refer to style callout. If style to out in the datasheet r datasheet pinout or p | ype is not called efer to the device |
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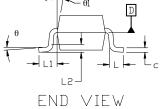
SOT-23, 5 Lead CASE 527AH **ISSUE A**

DATE 09 JUN 2021

NDTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 19894
- CONTROLLING DIMENSION: MILLIMETERS
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL
- DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.25 PER SIDE. D AND E1 DIMENSIONS ARE DETERMINED AT DATUM D.
- DIMENSION 'b' DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08mm TOTAL IN EXCESS OF THE 'b' DIMENSION AT MAXIMUM MATERIAL CONDITION. MINIMUM SPACE BETWEEN PROTRUSION AND AN ADJACENT LEAD SHALL NOT BE LESS THAN 0.07mm.





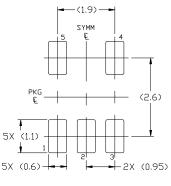
GENERIC **MARKING DIAGRAM***



XXX = Specific Device Code = Date Code М

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

| | MIL | MILLIMETERS | | | | |
|------------|----------|-------------|------|--|--|--|
| DIM | MIN. | NDM. | MAX. | | | |
| Α | 0.90 | — | 1.45 | | | |
| A1 | 0.00 | _ | 0.15 | | | |
| A2 | 0.90 | 1.15 | 1.30 | | | |
| b | 0.30 | — | 0.50 | | | |
| С | 0.08 | | 0.22 | | | |
| D | 2.90 BSC | | | | | |
| E | 2.80 BSC | | | | | |
| E1 | 1.60 BSC | | | | | |
| е | 0 | 0.95 BSC | | | | |
| L | 0.30 | 0.45 | 0.60 | | | |
| L1 | 0.60 REF | | | | | |
| L2 | 0.25 REF | | | | | |
| θ | 0* | 4° | 8* | | | |
| 01 | 0* | 10° | 15° | | | |
| θ 2 | 0° | 10° | 15° | | | |



RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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